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MM74HC04 Hex Inverter

Features

- Typical propagation delay: 8ns
- Fan out of 10 LS-TTL loads
- Quiescent power consumption: 10µW maximum at room temperature
- Low input current: 1µA maximum

General Description

The MM74HC04 inverters utilize advanced silicon-gate CMOS technology to achieve operating speeds similar to LS-TTL gates with the low power consumption of standard CMOS integrated circuits.

The MM74HC04 is a triple buffered inverter. It has high noise immunity and the ability to drive 10 LS-TTL loads. The 74HC logic family is functionally as well as pin-out compatible with the standard 74LS logic family. All inputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

Ordering Information

Order Number	Package Number	Package Description
MM74HC04M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC04SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HC04MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC04N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

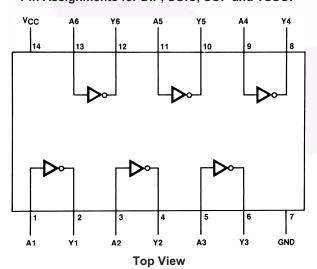
Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering number.



All packages are lead free per JEDEC: J-STD-020B standard.

Connection Diagram

Pin Assignments for DIP, SOIC, SOP and TSSOP



Logic Diagram

1 of 6 Inverters



Absolute Maximum Ratings⁽¹⁾

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Rating
V _{CC}	Supply Voltage	-0.5 to +7.0V
V _{IN}	DC Input Voltage	–1.5 to V _{CC} +1.5V
V _{OUT}	DC Output Voltage	–0.5 to V _{CC} +0.5V
I _{IK} , I _{OK}	Clamp Diode Current	±20mA
I _{OUT}	DC Output Current, per pin	±25mA
I _{CC}	DC V _{CC} or GND Current, per pin	±50mA
T _{STG}	Storage Temperature Range	−65°C to +150°C
P _D	Power Dissipation Note 2	600mW
	S.O. Package only	500mW
T_L	Lead Temperature (Soldering 10 seconds)	260°C

Notes:

- 1. Unless otherwise specified all voltages are referenced to ground.
- 2. Power Dissipation temperature derating plastic "N" package: -12mW/°C from 65°C to 85°C.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter	Min.	Max.	Units
V _{CC}	Supply Voltage	2	6	V
V _{IN} , V _{OUT}	DC Input or Output Voltage	0	V _{CC}	V
T _A	Operating Temperature Range	-40	+85	°C
t _r , t _f	Input Rise or Fall Times			
	$V_{CC} = 2.0V$		1000	ns
	V _{CC} = 4.5V		500	ns
	V _{CC} = 6.0V		400	ns

DC Electrical Characteristics⁽³⁾

				T _A =	25°C	T _A = -40°C to 85°C	T _A = -55°C to 125°C	
Symbol	Parameter	V _{CC} (V)	Conditions	Тур.		Guaranteed	Limits	Units
V _{IH}	Minimum HIGH Level	2.0			1.5	1.5	1.5	V
	Input Voltage	4.5			3.15	3.15	3.15	
		6.0			4.2	4.2	4.2	
V _{IL}	Maximum LOW Level	2.0			0.5	0.5	0.5	V
	Input Voltage	4.5			1.35	1.35	1.35	
		6.0			1.8	1.8	1.8	
V _{OH}	Minimum HIGH Level	2.0	$V_{IN} = V_{IL}$	2.0	1.9	1.9	1.9	V
	Output Voltage	4.5	I _{OUT} ≤ 20μA	4.5	4.4	4.4	4.4	
		6.0		6.0	5.9	5.9	5.9	
		4.5	$V_{IN} = V_{IL},$ $ I_{OUT} \le 4.0 \text{mA}$	4.2	3.98	3.84	3.7	
		6.0	$V_{IN} = V_{IL},$ $ I_{OUT} \le 5.2 \text{mA}$	5.7	5.48	5.34	5.2	
V _{OL}	Maximum LOW Level Output Voltage	2.0	$V_{IN} = V_{IH},$	0	0.1	0.1	0.1	V
		4.5	I _{OUT} ≤ 20μA	0	0.1	0.1	0.1	
		6.0		0	0.1	0.1	0.1	
		4.5	$V_{IN} = V_{IH},$ $ I_{OUT} \le 4.0 \text{mA}$	0.2	0.26	0.33	0.4	
		6.0	$V_{IN} = V_{IH},$ $ I_{OUT} \le 5.2 \text{mA}$	0.2	0.26	0.33	0.4	
I _{IN}	Maximum Input Current	6.0	$V_{IN} = V_{CC}$ or GND		±0.1	±1.0	±1.0	μA
I _{CC}	Maximum Quiescent Supply Current	6.0	$V_{IN} = V_{CC}$ or GND, $I_{OUT} = 0\mu A$		2.0	20	40	μA

Note:

3. For a power supply of 5V $\pm 10\%$ the worst case output voltages (V_{OH}, and V_{OL}) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at V_{CC} = 5.5V and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage current (I_{IN}, I_{CC}, and I_{OZ}) occur for CMOS at the higher voltage and so the 6.0V values should be used.

AC Electrical Characteristics

 $V_{CC}=5V,\ T_A=25^{\circ}C,\ C_L=15pF,\ t_r=t_f=6ns$

Symbol	Parameter	Conditions	Тур.	Guaranteed Limit	Units
t_{PHL} , t_{PLH}	Maximum Propagation Delay		8	15	ns

AC Electrical Characteristics

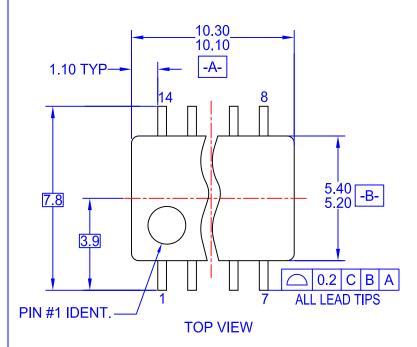
 V_{CC} = 2.0V to 6.0V, C_L = 50pF, t_r = t_f = 6ns (unless otherwise specified)

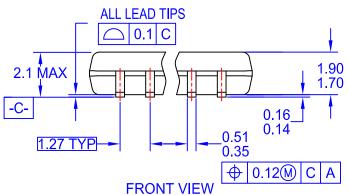
				T _A =	25°C	T _A = -40°C to 85°C	T _A = -55°C to 125°C	
Symbol	Parameter	V _{CC} (V)	Conditions	Тур.		Guaranteed Limits		
t _{PHL} , t _{PLH}	Maximum	2.0		55	95	120	145	ns
	Propagation Delay	4.5		11	19	24	29	
		6.0		9	16	20	24	1
t _{TLH} , t _{THL}	Maximum Output Rise and Fall Time	2.0		30	75	95	110	ns
		4.5		8	15	19	22	1
		6.0		7	13	16	19	1
C _{PD}	Power Dissipation Capacitance ⁽⁴⁾		(per gate)	20				pF
C _{IN}	Maximum Input Capacitance			5	10	10	10	pF

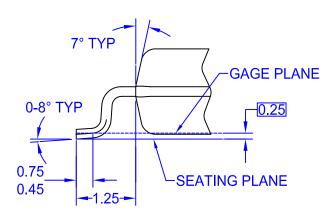
Note

4. C_{PD} determines the no load dynamic power consumption, $P_D = C_{PD} \ V_{CC}^2 \ f + I_{CC} \ V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} \ V_{CC} \ f + I_{CC}$.

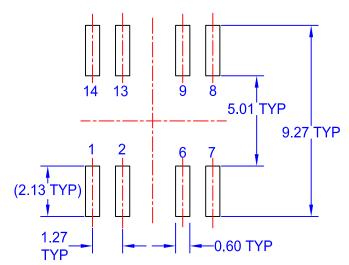




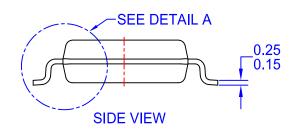




DETAIL A



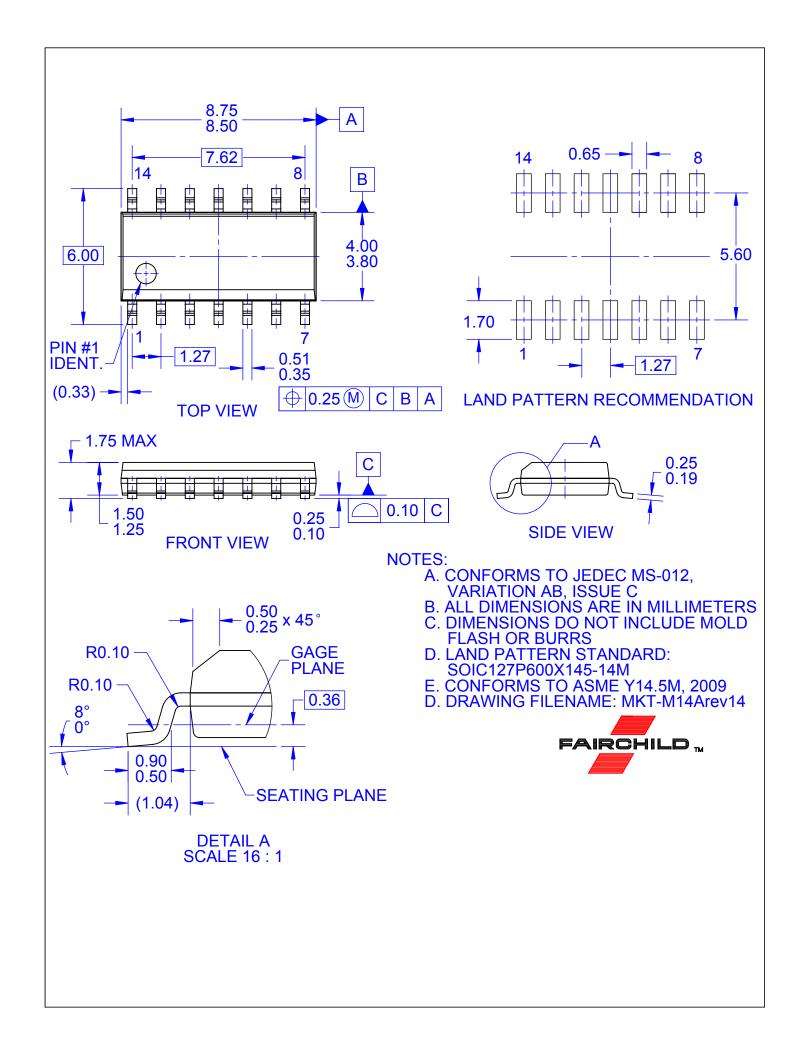
LAND PATTERN RECOMMENDATION



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